



Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt®

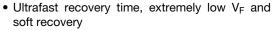




D-PAK (TO-252AA)

PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	6 A						
V_R	600 V						
V _F at I _F	1.25 V						
t _{rr} (typ.)	59 ns						
T _J max.	175 °C						
Diode variation	Single die						

FEATURES





• For PFC DCM operation

· Low leakage current

Compliant to RoHS Directive 2002/95/EC

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

• Halogen-free according to IEC 61249-2-21 definition







FREE

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Peak repetitive reverse voltage	V_{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 156 °C	6					
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	80	Α				
Peak repetitive forward current	I _{FM}	$T_C = 156 ^{\circ}\text{C}, f = 20 \text{kHz}, d = 50 \%$	12					
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I ID = 100 UA		-	-				
Forward voltage	V _F	I _F = 6 A	-	0.99	1.25	V			
		I _F = 6 A, T _J = 150 °C	-	0.87	1.05				
Deviana leekaan eriment	I _R	V _R = V _R rated	-	-	5				
Reverse leakage current		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$		125	μΑ				
Junction capacitance	C _T	V _R = 600 V	-	3.5	=	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH			

VS-6EWL06FN-M3

Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt®



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, dI_F/dt = 10$	$00 \text{ A/}\mu\text{s}, V_{\text{R}} = 30 \text{ V}$	-	59	70			
		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	75	-			
	t _{rr}	T _J = 25 °C		-	154	-	ns		
		T _J = 125 °C		-	215	-			
Peak recovery current	$T_J = 25 ^{\circ}\text{C}$ $I_F = 6A$	-	13.3	-	Α				
reak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 200 A/µs V _R = 390 V	-	15.4	-			
Reverse recovery charge	0	T _J = 25 °C		-	1055	-	nC		
	Q _{rr}	T _J = 125 °C		-	1600	-			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C				
Thermal resistance, junction to case per leg	R _{thJC}		-	-	3	°C/W				
Approximate weight				0.3		g				
Approximate weight				0.01		OZ.				
Marking device		Case style D-PAK (TO-252AA)	6EWL06FN							



Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt®

Vishay Semiconductors

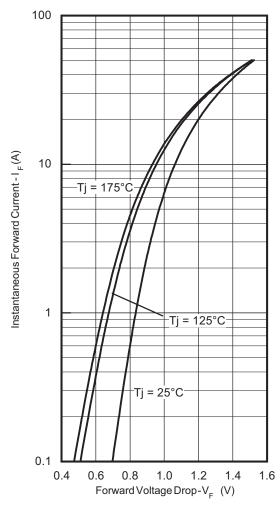


Fig. 1 - Typical Forward Voltage Drop Characteristics

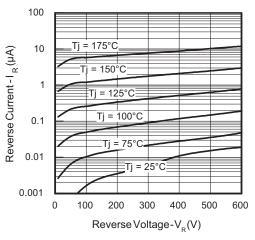


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

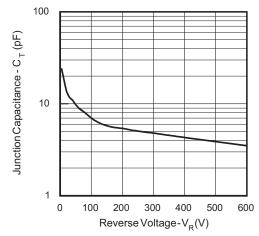


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

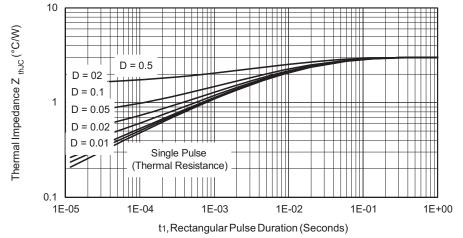


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

VS-6EWL06FN-M3

Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt®



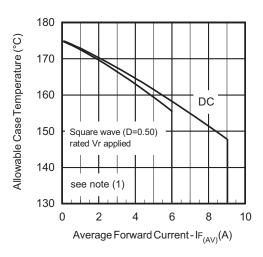


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

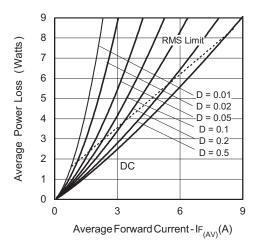


Fig. 6 - Forward Power Loss Characteristics

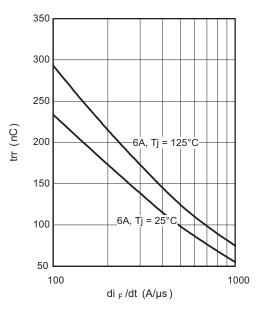


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

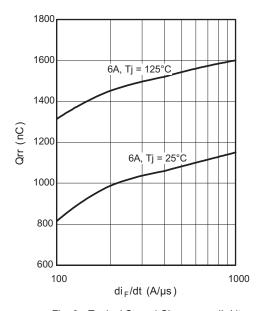


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R



Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt®

Vishay Semiconductors

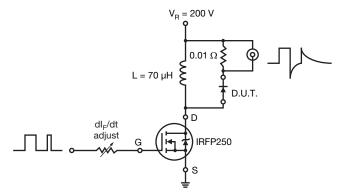
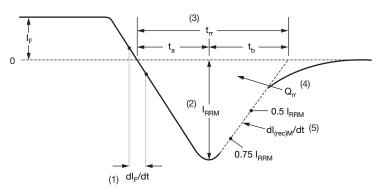


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

VS-6EWL06FN-M3

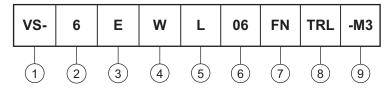
Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt®



ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (6 = 6 A)
- Circuit configuration:
 - E = Single diode
- 4 Package identifier:
 - W = D-PAK
- 5 L = Low V_F, fast recovery
- 6 Voltage rating (06 = 600 V)
- 7 FN = TO-252AA
- 8 • None = Tube
 - TR = Tape and reel
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-6EWL06FN-M3	75	3000	Antistatic plastic tube						
VS-6EWL06FNTR-M3	2000	2000	13" diameter reel						
VS-6EWL06FNTRL-M3	3000	3000	13" diameter reel						
VS-6EWL06FNTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?95016</u>							
Part marking information	www.vishay.com/doc?95176						
SPICE model	www.vishay.com/doc?95218						



Vishay Semiconductors

INCHES

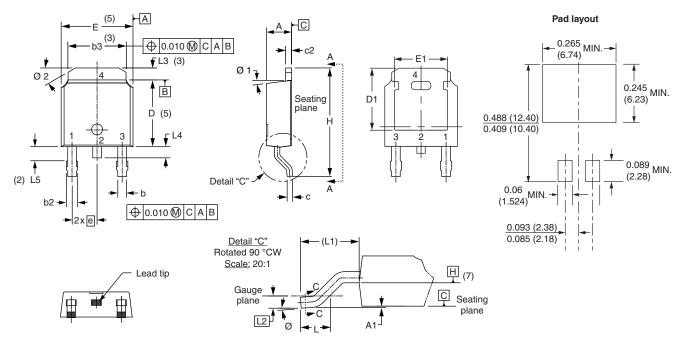
MIN.

MAX.

NOTES

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES		SYMBOL	MILLIMETERS		
STIVIBUL	MIN.	MAX.	MIN.	MAX.				MIN.	MAX.	
Α	2.18	2.39	0.086	0.094			е	2.29	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	
c2	0.46	0.89	0.018	0.035			L4	-	1.02	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	
D1	5.21	-	0.205	-	3		Ø	0°	10°	
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	

е	2.29	2.29 BSC		0.090 BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	BSC	0.108	REF.	
L2	0.51	BSC	0.020	BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	·
Ø2	25°	35°	25°	35°	·
	H L1 L2 L3 L4 L5 Ø	H 9.40 L 1.40 L1 2.74 L2 0.51 L3 0.89 L4 - L5 1.14 Ø 0° Ø1 0°	H 9.40 10.41 L 1.40 1.78 L1 2.74 BSC L2 0.51 BSC L3 0.89 1.27 L4 - 1.02 L5 1.14 1.52 Ø 0° 10° Ø1 0° 15°	H 9.40 10.41 0.370 L 1.40 1.78 0.055 L1 2.74 BSC 0.108 L2 0.51 BSC 0.020 L3 0.89 1.27 0.035 L4 - 1.02 - L5 1.14 1.52 0.045 Ø 0° 10° 0° Ø1 0° 15° 0°	H 9.40 10.41 0.370 0.410 L 1.40 1.78 0.055 0.070 L1 2.74 BSC 0.108 REF. L2 0.51 BSC 0.020 BSC L3 0.89 1.27 0.035 0.050 L4 - 1.02 - 0.040 L5 1.14 1.52 0.045 0.060 Ø 0° 10° 0° 10° Ø1 0° 15° 0° 15°

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000